ASSP

CMOS

30 MHz 8-bit A/D Converter

MB40C238

■ DESCRIPTION

MB40C238 is a high-speed converter using a fast CMOS technology.

■ FEATURES

• Resolution : 8 bit

Linearity error
 Differential linearity error
 Maximum conversion rate
 Power supply voltage
 Digital input voltage range
 ±0.2% (standard)
 ±0.12% (standard)
 30 MSPS (minimum)
 +3.0 V (single)
 3 V CMOS level

• Digital output voltage range : 3 V CMOS level compatible (tristate output)

• Analog input voltage range : 0 to 2.0 V (1.2 to 1.8 Vp-p)

• Analog input capacitance : 15 pF (standard)

Power dissipation
 Additional features
 50 mW (standard: including reference current)
 VRT voltage adjustment amp (VRT = 1.2 to 2.0 V)

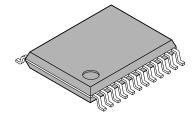
Power saving capacity (also reference current set to OFF: 0.5 mW or less)

High impedance output

• Package : 24-pin SSOP

■ PACKAGE

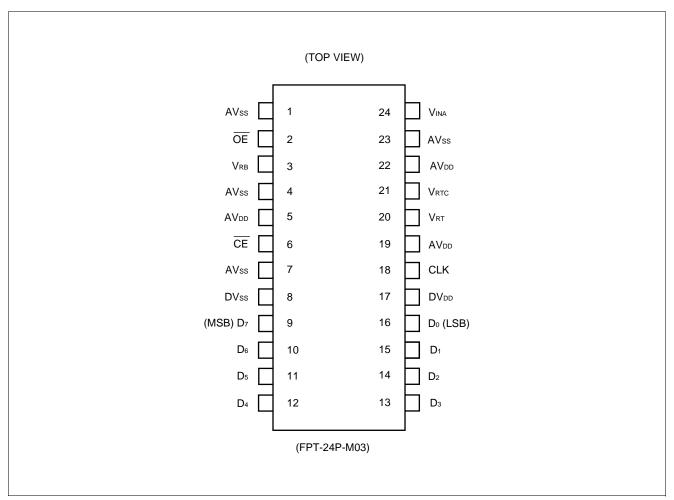
24-pin Plastic SSOP



(FPT-24P-M03)

MB40C238

■ PIN ASSIGNMENT



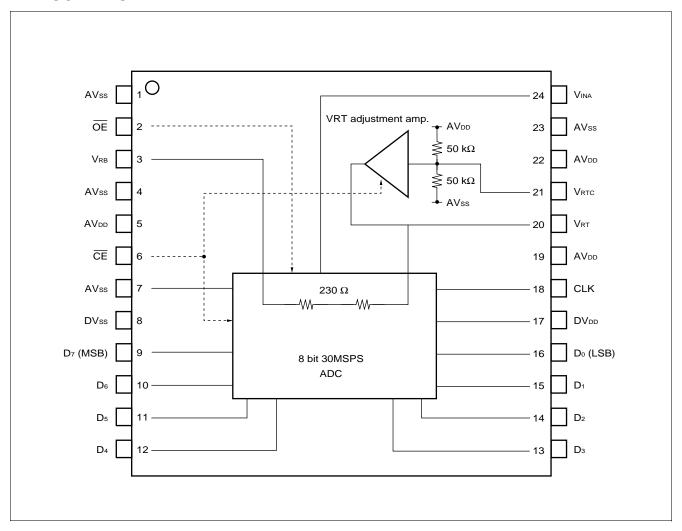
■ PIN DESCRIPTION

Pin No.	Symbol	Description
5, 19, 22	AV _{DD}	Analog power supply (+3.0 V)
17	DV _{DD}	Digital power supply (+3.0 V)
1, 4, 7, 23	AVss	Analog power supply ground pin (0 V)
8	DVss	Digital power supply ground pin (0 V)
9, 10, 11, 12, 13, 14, 15, 16	D ₇ to D ₀	Digital output pin (D ₇ : MSB, D ₀ : LSB)
18	CLK	Clock input pin
24	VINA	A/D converter analog input pin Input range is VRB to VRT (0 to 1.5 V: standard)
21	VRTC	VRT voltage adjustment amp input pin (VRTC: 1.5 V is output when opened.)
20	V _{RT}	Reference voltage output pin on top side. The voltage fed to VRTC is output. (1.5 V: standard)
3	V _{RB}	Reference voltage input pin on bottom side (0 V: standard)
6	CE	Input pin for toggling standby function. Input high signal brings the ADC and reference voltage circuit.
2	OE	Input pin for toggling output high impedance function. Input high signal brings the ADC output high impedance state.

Note: The values in parentheses are standard.

MB40C238

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Rat	Unit	
Farameter	Symbol	Min.	Max.	Offic
Power supply voltage	AVDD, DVDD	-0.3	+7.0	V
Input voltage (analog/digital)	CLK, VINA, VRTC, VRB	-0.3	AVDD+0.3	V
Output voltage	D ₀ to D ₇	-0.3	DV _{DD} +0.3	V
Output voltage	VRT	-0.3	AV _{DD} +0.3	V
Storage temperature	Tstg	- 55	+125	°C

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Value			Unit	
Parameter	Syllibol	Min.	Тур.	Max.	- Offic	
	AV _{DD}	2.70	3.00	3.60	V	
Power supply voltage	DV _{DD}	2.70	3.00	3.60	V	
	AVDD - DVDD	0.0	_	0.2	V	
Analog input voltage	VINA	V _{RB}	_	V _{RT}	V	
Analog reference voltage: T	VRTC	1.2	1.5	2.0	V	
Analog reference voltage: B	V _{RB}	0.0	_	0.8	V	
Analog reference voltage range	V _{RT} – V _{RB}	1.2	1.5	1.8	V	
Digital "H" level input voltage	VIHD	2.3	_	_	V	
Digital "L" level input voltage	VILD	_	_	0.5	V	
Digital input current	lıp	_	_	5	μΑ	
Clock frequency	fclk	0.5	_	30	MHz	
"H" level minimum clock pulse width	tw +	16.0	_	_	ns	
"L" level minimum clock pulse width	tw -	16.0	_	_	ns	
Operating temperature range	Та	-20	_	+75	°C	

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

> Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

> No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

■ ELECTRICAL CHARACTERISTICS

1. DC Characteristics in Analog Section

 $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, DV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, Ta = -20^{\circ}\text{C to } +75^{\circ}\text{C})$

Parameter		Symbol	Value			Unit
Paramet	Symbol	Min.	Тур.	Max.	Unit	
Resolution		_	_	8	_	bit
Linearity error	Conditional DC	LE	_	±0.20	±0.40	%
Differential linearity error	precision $V_{RT} - V_{RB} = 1.5 \text{ V}$	DLE	_	±0.12	±0.20	%
Analog input capacity		CINA	_	15	_	pF
Reference input voltage (Top side) (VRTC opened)		VRTC	_	$0.50 \times AV_{DD}$	_	V
Reference output voltage (Top side)		V _{RT}	_	VRTC	_	V
Reference current (Bottom side)		IRВ	_	6.5	_	mA
Analog supply current		Aldd	_	14.0	34.0	mA
Digital supply current		DI _{DD}	_	3.0	7.0	mA
Standby supply current		Іѕтва	_	100	_	μΑ
		ISTBD		1	_	μΑ

2. DC Characteristics in Digital Section

 $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, DV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, Ta = -20^{\circ}\text{C to } +75^{\circ}\text{C})$

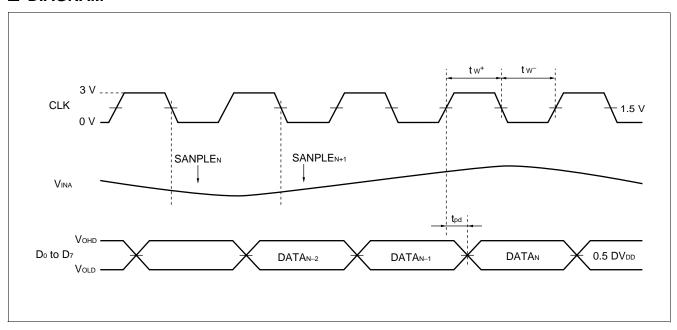
Parameter	Symbol	Value			Unit
raiametei		Min.	Тур.	Max.	Offic
Digital "H" level output voltage	Vohd	2.4	_	DV _{DD}	V
Digital "L" level output voltage	Vold	_	_	0.4	V
Digital "H" level output current	lонd	-400	_	_	μΑ
Digital "L" level output current	lold	_	_	1.6	mA

3. Switching Characteristics

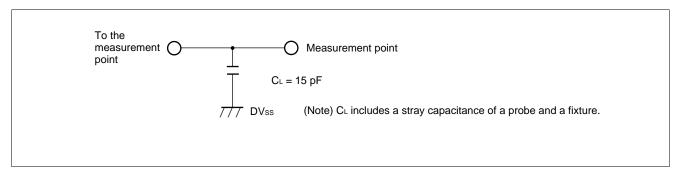
 $(AV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, DV_{DD} = 2.70 \text{ V to } 3.60 \text{ V}, Ta = -20^{\circ}\text{C to } +75^{\circ}\text{C})$

Parameter	Symbol		Unit		
Farameter		Min.	Тур.	Max.	Onit
Maximum conversion rate	fs	30	_	_	MSPS
Digital output delay time	t _{pd}	3	8	20	ns

■ DIAGRAM



■ DIGITAL OUTPUT BUFFER LOAD CIRCUIT



■ USAGE PRECAUTIONS

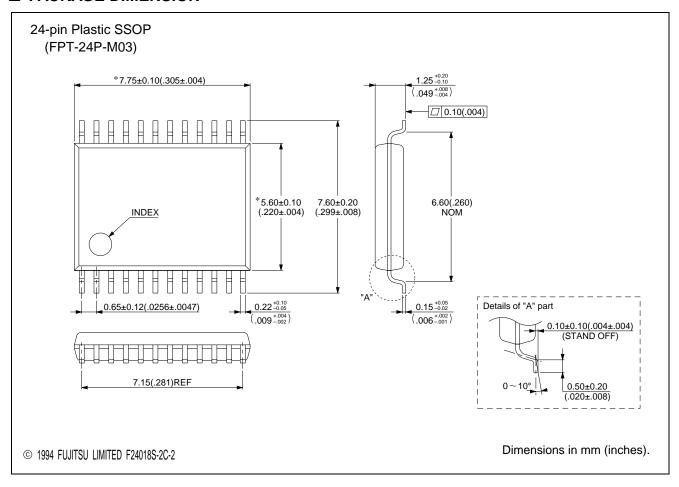
- Be sure to ground the pins of AV_{DD}, DV_{DD}, V_{RT} and V_{RB} via high-frequency capacitor. Place the high-frequency capacitor as close as possible to the pin.
- You can minimize the power supply current dissipation due to the internal logic indetermination by making the clock to 4CLK or higher.

MB40C238

■ ORDERING INFORMATION

Part number	Package	Remark
MB40C238PFV	24-pin Plastic SSOP (FPT-24P-M03)	

■ PACKAGE DIMENSION



FUJITSU LIMITED

For further information please contact:

Japan

FUJITSU LIMITED

Corporate Global Business Support Division

Electronic Devices

KAWASAKI PLANT, 4-1-1, Kamikodanaka

Nakahara-ku, Kawasaki-shi Kanagawa 211-8588, Japan

Tel: 81(44) 754-3763 Fax: 81(44) 754-3329

http://www.fujitsu.co.jp/

North and South America

FUJITSU MICROELECTRONICS, INC.

Semiconductor Division 3545 North First Street

San Jose, CA 95134-1804, USA

Tel: (408) 922-9000 Fax: (408) 922-9179

Customer Response Center Mon. - Fri.: 7 am - 5 pm (PST)

Tel: (800) 866-8608 Fax: (408) 922-9179

http://www.fujitsumicro.com/

Europe

FUJITSU MIKROELEKTRONIK GmbH Am Siebenstein 6-10

D-63303 Dreieich-Buchschlag

Germany

Tel: (06103) 690-0 Fax: (06103) 690-122

http://www.fujitsu-ede.com/

Asia Pacific

FUJITSU MICROELECTRONICS ASIA PTE LTD

#05-08, 151 Lorong Chuan New Tech Park

Singapore 556741 Tel: (65) 281-0770 Fax: (65) 281-0220

http://www.fmap.com.sg/

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